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Title	親水性向上を伴うルチル型二酸化チタン上ヘテロエピ タキシャル成長酸化シリコン層のナノスケール表面解 析
Author(s)	LE, TRAN UYEN TU
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Japan Advanced Institute of Science and Technology

## Abstract

Titanium dioxide (TiO<sub>2</sub>)-based substrates and added silicon oxide (SiO<sub>2</sub>) layers are the subjects of an extensive research aiming at applications to photocatalysts for environmental purification, photoinduced superhydrophilic coatings, and electrodes of dye-sensitized photochemical solar cells. The SiO<sub>2</sub>-TiO<sub>2</sub> composite system is promising to extend the lifetime of the hydrophilicity in dark, which is activated with UV light irradiation. Control of the crystalline structures and thickness of SiO<sub>2</sub> layers deposited on TiO<sub>2</sub> surfaces can enhance their unique physical and chemical properties. To date various kinds of SiO<sub>2</sub>-TiO<sub>2</sub> systems have been studied using a range of different techniques, including sol-gel dip coating, evaporation-induced self-assembly using dip-coating, electrochemical deposition, and ion milling. Nevertheless, most of the techniques cannot control side reactions nor film homogeneity on a nanoscale. Thus, it is keenly expected to reveal the mechanism of their fascinating phenomena fully using surface analytical methods by combining with sample preparation methods to prepare well-defined surfaces of SiO<sub>2</sub>-TiO<sub>2</sub> systems.

In this study, silicon oxide growth on a single crystal rutile  $TiO_2(110)$  surface by annealing in a quartz case (SiO<sub>2</sub>) in air at 1000°C is characterized by X-ray photoemission spectroscopy (XPS), low energy electron diffraction (LEED), frequency modulation-atomic force microscopy (FM-AFM) operated in pure water. Furthermore, to confirm the growth of silicon oxide by SiO vapor from the quartz case, we anneal the TiO<sub>2</sub> substrate stored in a single crystal sapphire case (Al<sub>2</sub>O<sub>3</sub>), from which no SiO vapor comes out, as a control experiment. We evaluate the hydrophilicity of the silicon oxide overlayers on the TiO<sub>2</sub> surface by water contact angle (WCA) measurement. This leads us to fundamental understanding of the relationship between nano-scale surface features and its wettability, which is useful to improve the characteristics of industrial and ecological products using TiO<sub>2</sub>.

XPS analysis for the silicon oxide deposited on  $TiO_2(110)$  were as follows: contamination were found for as-received  $TiO_2(110)$ , and disappeared after chemical cleaning and annealing processes in both quartz case and sapphire case. On one hand, Si 2s and 2p XPS peaks found for samples annealed in the quartz case were not observed for annealed in the sapphire case. The shoulders on the higher binding energy side of each O peak were assigned to either hydroxyl group or O atoms bonded to Si and Ti. The hydroxyl group can be associated with water hydrophilicity. The existence and increasing of the Si XPS peak with annealing time as well as the change of LEED patterns of  $TiO_2(110)$  periodicity from (1x1) to (1x2) indicated the formation of epitaxial growth of silicon oxide ultra-thin layers on  $TiO_2(110)$  substrate. The patches were found in FM-AFM images of annealed  $TiO_2$  in quartz case, which are attributed to the SiO<sub>2</sub> growth: rectangular shaped patches were grown with extending annealing time.

Water wettability measurements showed that the surface annealed in sapphire, corresponding to a fully oxidized stoichiometric surface, was less hydrophilic at a WCA of 32°. Due to photocatalytic nature, TiO<sub>2</sub>(110) surfaces were strongly affected by UV irradiation, showing superhydrophilicity. As in a large amount of literature, the hydrophilicity quickly disappears when those are stored in dark. On the other hand, SiO<sub>2</sub>/TiO<sub>2</sub> surfaces formed by vapor phase epitaxial deposition in air displayed more hydrophilic. In particular for 72 hours annealing, the SiO<sub>2</sub>/TiO<sub>2</sub> surface showed super-hydrophilic without UV illumination. The super-hydrophilicity corresponds to the saturated Si peak height in XPS analysis, the transition of atomic periodicity from  $(1\times1)$  to  $(1\times2)$  in the LEED pattern, and the rectangular patch formation of silicon oxide. Moreover, the ability of the sample annealed for 72 hours to maintain hydrophilicity was greater than that of TiO<sub>2</sub>(110) surfaces annealed for shorter time. This is probably attributed to the hardness and durability of top most silicon oxide layer as well as the photo-catalytic power of sub-surface TiO<sub>2</sub>(110) surface. An atomic model of SiO<sub>2</sub>/TiO<sub>2</sub> surface was proposed to elucidate the relationship between the change in atomistic characteristics at the surfaces and the conversion of hydrophobic/hydrophilic properties of SiO<sub>2</sub>/TiO<sub>2</sub> systems.

In this study, we demonstrated to distinctly fabricate a fully oxidized  $TiO_2(110)$ -(1x1) surface and ultra-thin layers of SiO<sub>2</sub> hetero-epitaxially grown on a rutile  $TiO_2(110)$  surface by annealing in air in different cases of sapphire and quartz, in which the substrate was stored. Their structures and characteristics were analyzed on a nano-scale, and the surface wettability was examined; the correlations between them were discussed to disclose the fascinating properties of titanium dioxide and silicon dioxide systems. The findings in this study suggest the potential of conventional hetero-epitaxial growth of oxides by vapor phase transport in air, and shed light on the mechanism of super-hydrophilicity utilized in commercial products such as anti-fog mirrors of SiO<sub>2</sub>-TiO<sub>2</sub> hybrid materials.

Key words: titanium dioxide, silicon dioxide, hetero-epitaxy, stishovite, super-hydrophilicity.